

# 1, 2 and 4-Channel Low Capacitance ESD Protection Arrays

## CM1213A, SZCM1213A

### Product Description

The CM1213A family of diode arrays has been designed to provide ESD protection for electronic components or subsystems requiring minimal capacitive loading. These devices are ideal for protecting systems with high data and clock rates or for circuits requiring low capacitive loading. Each ESD channel consists of a pair of diodes in series which steer the positive or negative ESD current pulse to either the positive ( $V_P$ ) or negative ( $V_N$ ) supply rail. A Zener diode is embedded between  $V_P$  and  $V_N$ , offering two advantages. First, it protects the  $V_{CC}$  rail against ESD strikes, and second, it eliminates the need for a bypass capacitor that would otherwise be needed for absorbing positive ESD strikes to ground. The CM1213A will protect against ESD pulses up to 12 kV per the IEC 61000-4-2 standard.

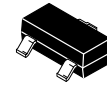
### Features

- One, Two, and Four Channels of ESD Protection  
Note: For 6 and 8-channel Devices, See the CM1213 Data Sheet
- Provides ESD Protection to IEC61000-4-2 Level 4
  - ◆  $\pm 12$  kV Contact Discharge
- Low Channel Input Capacitance of 0.85 pF Typical
- Minimal Capacitance Change with Temperature and Voltage
- Channel Input Capacitance Matching of 0.02 pF Typical is Ideal for Differential Signals
- Each CH (I/O) Pin Can Withstand Over 1000 ESD Strikes\*
- SZ Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

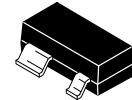
### Applications

- USB2.0 Ports at 480 Mbps in Desktop PCs, Notebooks and Peripherals
- IEEE1394 Firewire® Ports at 400 Mbps/800 Mbps
- DVI Ports, HDMI Ports in Notebooks, Set Top Boxes, Digital TVs, LCD Displays
- Serial ATA Ports in Desktop PCs and Hard Disk Drives
- PCI Express Ports
- General Purpose High-Speed Data Line ESD Protection

\*Standard test condition is IEC61000-4-2 level 4 test circuit with each pin subjected to  $\pm 8$  kV contact discharge for 1000 pulses. Discharges are timed at 1 second intervals and all 1000 strikes are completed in one continuous test run. The part is then subjected to standard production test to verify that all of the tested parameters are within spec after the 1000 strikes.



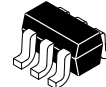
SOT23-3  
SO SUFFIX  
CASE 318



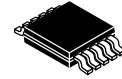
SOT-143  
SR SUFFIX  
CASE 318A



SC-74  
SO SUFFIX  
CASE 318F

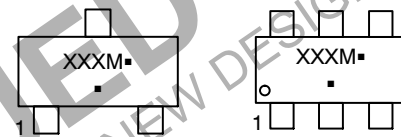


SC70-6  
S7 SUFFIX  
CASE 419AD

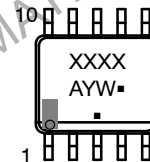


MSOP-10  
MR SUFFIX  
CASE 846AE

### MARKING DIAGRAMS



XXX = Specific Device Code  
M = Date Code  
▪ = Pb-Free Package



XXXX = Specific Device Code  
A = Assembly Location  
Y = Year  
W = Work Week  
▪ = Pb-Free Package

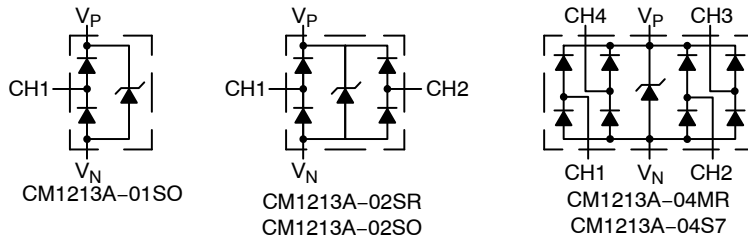
(Note: Microdot may be in either location)

### ORDERING INFORMATION

See detailed ordering, marking and shipping information on page 2 of this data sheet.

# CM1213A, SZCM1213A

## BLOCK DIAGRAM



**Table 1. ORDERING INFORMATION**

| Device          | Marking | Package               | Shipping†           |
|-----------------|---------|-----------------------|---------------------|
| CM1213A-01SO    | 231     | SOT23-3<br>(Pb-Free)  | 3,000 / Tape & Reel |
| SZCM1213A-01SO* |         |                       |                     |
| CM1213A-02SR    | D232    | SOT143-4<br>(Pb-Free) | 3,000 / Tape & Reel |
| SZCM1213A-02SR* |         |                       |                     |
| CM1213A-02SO    | 233     | SC-74<br>(Pb-Free)    | 3,000 / Tape & Reel |
| CM1213A-04S7    | D38     | SC70-6<br>(Pb-Free)   | 3,000 / Tape & Reel |
| CM1213A-04MR    | D237    | MSOP-10<br>(Pb-Free)  | 4,000 / Tape & Reel |

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

\*SZ Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable.

DISCONTINUED

THIS DEVICE IS NOT RECOMMENDED FOR NEW DESIGN  
PLEASE CONTACT YOUR ONSEMI REPRESENTATIVE FOR INFORMATION

# CM1213A, SZCM1213A

**Table 2. PIN DESCRIPTIONS**

| 1-Channel, 3-Lead SOT23-3 Package (CM1213A-01SO) |                |      |                              |
|--|----------------|------|------------------------------|
| Pin  | Name           | Type | Description                  |
| 1  | CH1            | I/O  | ESD Channel                  |
| 2  | V <sub>P</sub> | PWR  | Positive Voltage Supply Rail |
| 3  | V <sub>N</sub> | GND  | Negative Voltage Supply Rail |

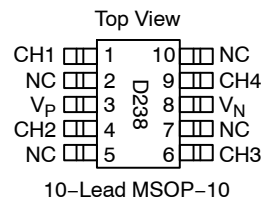
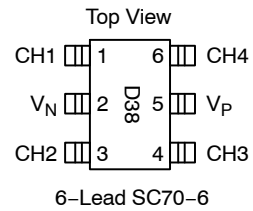
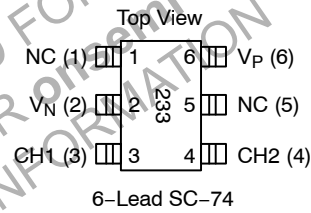
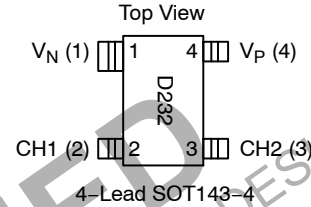
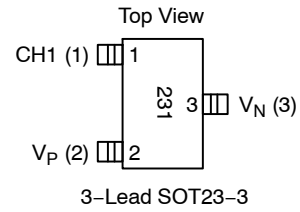
| 2-Channel, 4-Lead SOT143-4 Package (CM1213A-02SR) |                |      |                              |
|---|----------------|------|------------------------------|
| Pin   | Name           | Type | Description                  |
| 1   | V <sub>N</sub> | GND  | Negative Voltage Supply Rail |
| 2   | CH1            | I/O  | ESD Channel                  |
| 3   | CH2            | I/O  | ESD Channel                  |
| 4   | V <sub>P</sub> | PWR  | Positive Voltage Supply Rail |

| 2-Channel, SC-74 Package (CM1213A-02SO) |                |      |                              |
|---|----------------|------|------------------------------|
| Pin                                     | Name           | Type | Description                  |
| 1                                       | NC             | -    | No Connect                   |
| 2                                       | V <sub>N</sub> | GND  | Negative Voltage Supply Rail |
| 3                                       | CH1            | I/O  | ESD Channel                  |
| 4                                       | CH2            | I/O  | ESD Channel                  |
| 5                                       | NC             | -    | No Connect                   |
| 6                                       | V <sub>P</sub> | PWR  | Positive Voltage Supply Rail |

| 4-Channel, 6-Lead SC70-6 (CM1213A-04S7) |                |      |                              |
|---|----------------|------|------------------------------|
| Pin                                     | Name           | Type | Description                  |
| 1                                       | CH1            | I/O  | ESD Channel                  |
| 2                                       | V <sub>N</sub> | GND  | Negative Voltage Supply Rail |
| 3                                       | CH2            | I/O  | ESD Channel                  |
| 4                                       | CH3            | I/O  | ESD Channel                  |
| 5                                       | V <sub>P</sub> | PWR  | Positive Voltage Supply Rail |
| 6                                       | CH4            | I/O  | ESD Channel                  |

| 4-Channel, 10-Lead MSOP-10 Package (CM1213A04MR) |                |      |                              |
|--|----------------|------|------------------------------|
| Pin  | Name           | Type | Description                  |
| 1  | CH1            | I/O  | ESD Channel                  |
| 2  | NC             | -    | No Connect                   |
| 3  | V <sub>P</sub> | PWR  | Positive Voltage Supply Rail |
| 4  | CH2            | I/O  | ESD Channel                  |
| 5  | NC             | -    | No Connect                   |
| 6  | CH3            | I/O  | ESD Channel                  |
| 7  | NC             | -    | No Connect                   |
| 8  | V <sub>N</sub> | GND  | Negative Voltage Supply Rail |
| 9  | CH4            | I/O  | ESD Channel                  |
| 10   | NC             | -    | No Connect                   |

**PACKAGE/PINOUT DIAGRAMS**



# CM1213A, SZCM1213A

## SPECIFICATIONS

**Table 3. ABSOLUTE MAXIMUM RATINGS**

| Parameter  | Rating  | Units |
|--|---|-------|
| Operating Supply Voltage ( $V_P - V_N$ )   | 5.5   | V     |
| Operating Temperature Range  | -40 to +150   | °C    |
| Storage Temperature Range  | -65 to +150   | °C    |
| DC Voltage at any channel input  | $(V_N - 0.5)$ to $(V_P + 0.5)$                          | V     |
| Package Power Rating<br>SOT23-3, SOT143-4, SC-74, and SC70-6 Packages<br>MSOP-10 Package   | 225<br>400  | mW    |
| ESD<br>IEC 61000-4-2 Contact<br>IEC 61000-4-2 Air<br>ISO 10605 330 pF / 330 $\Omega$ Contact<br>ISO 10605 330 pF / 2 k $\Omega$ Contact<br>ISO 10605 150 pF / 2 k $\Omega$ Contact | $\pm 12$<br>$\pm 12$<br>$\pm 9$<br>$\pm 22$<br>$\pm 25$ | kV    |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

**Table 4. ELECTRICAL OPERATING CHARACTERISTICS** (Note1)

| Symbol              | Parameter   | Conditions   | Min          | Typ          | Max          | Units    |
|---------------------|---|--|--------------|--------------|--------------|----------|
| $V_P$ ( $V_{RWM}$ ) | Operating Supply Voltage ( $V_P - V_N$ )                            |  |              | 3.3          | 5.5          | V        |
| $I_P$               | Operating Supply Current  | $V_P$ pin to $V_N$ pin, ( $V_P = 3.3$ V, $V_N = 0$ V)                          |              |              | 8.0          | $\mu$ A  |
| $I_{LEAK}$          | Channel Leakage Current   | CH pin to $V_N$ pin, $T_A = 25^\circ\text{C}$ ;<br>( $V_P = 5$ V, $V_N = 0$ V) |              | 0.1          | 1.0          | $\mu$ A  |
| $V_F$               | Diode Forward Voltage<br>Top Diode<br>Bottom Diode                  | $I_F = 8$ mA, $T_A = 25^\circ\text{C}$   | 0.60<br>0.60 | 0.80<br>0.80 | 0.95<br>0.95 | V        |
| $V_{BR}$            | Breakdown Voltage   | $I_T = 10$ mA, CH pin to $V_N$ pin   | 6.5          |              | 9.0          | V        |
| $C_{IN}$            | Channel Input Capacitance   | At 1 MHz, $V_P = 3.3$ V, $V_N = 0$ V, $V_{IN} = 1.65$ V<br>(Note 2)            |              | 0.85         | 1.2          | pF       |
| $\Delta C_{IN}$     | Channel Input Capacitance Matching                                  | At 1 MHz, $V_P = 3.3$ V, $V_N = 0$ V, $V_{IN} = 1.65$ V<br>(Note 2)            |              | 0.02         |              | pF       |
| $V_{CL}$            | Channel Clamp Voltage<br>Positive Transients<br>Negative Transients | $T_A = 25^\circ\text{C}$ , $I_{PP} = 1$ A, $t_P = 8/20$ $\mu$ s<br>(Note 2)    |              | +10<br>-1.7  |              | V        |
| $R_{DYN}$           | Dynamic Resistance<br>Positive Transients<br>Negative Transients    | $I_{PP} = 1$ A, $t_P = 8/20$ $\mu$ s<br>Any I/O pin to Ground<br>(Note 2)      |              | 0.9<br>0.5   |              | $\Omega$ |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

- All parameters specified at  $T_A = 25^\circ\text{C}$  unless otherwise noted.
- Standard IEC 61000-4-2 with  $C_{Discharge} = 150$  pF,  $R_{Discharge} = 330$   $\Omega$ ,  $V_P = 3.3$  V,  $V_N$  grounded.
- These measurements performed with no external capacitor on  $V_P$  ( $V_P$  floating).

# CM1213A, SZCM1213A

## PERFORMANCE INFORMATION

### Input Channel Capacitance Performance Curves

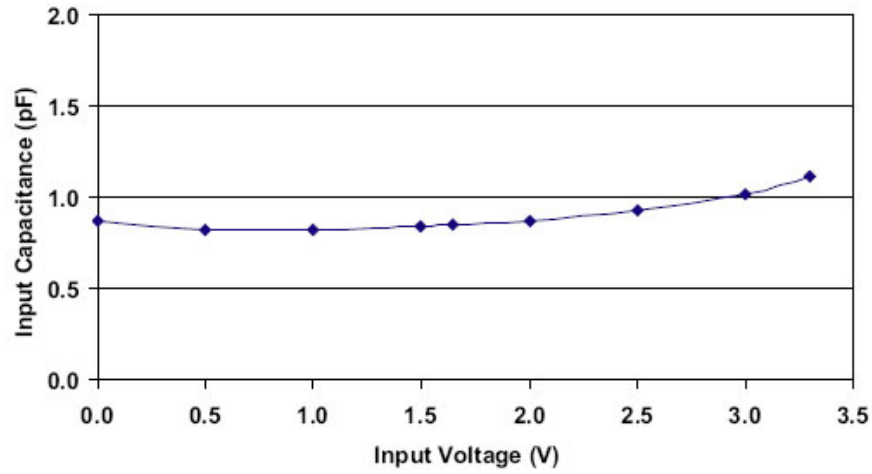


Figure 1. Typical Variation of  $C_{IN}$  vs.  $V_{IN}$   
( $f = 1 \text{ MHz}$ ,  $V_P = 3.3 \text{ V}$ ,  $V_N = 0 \text{ V}$ ,  $0.1 \mu\text{F}$  Chip Capacitor between  $V_P$  and  $V_N$ ,  $25^\circ\text{C}$ )

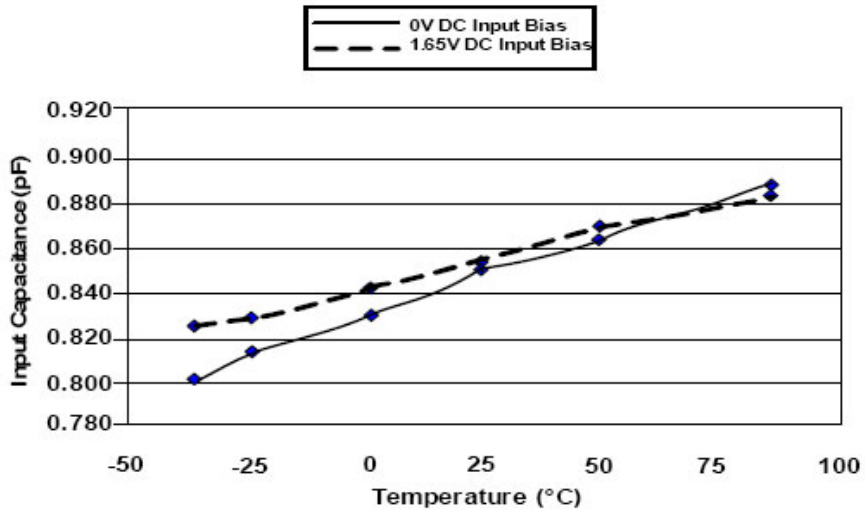


Figure 2. Typical Variation of  $C_{IN}$  vs. Temp  
( $f = 1 \text{ MHz}$ ,  $V_{IN} = 30 \text{ mV}$ ,  $V_P = 3.3 \text{ V}$ ,  $V_N = 0 \text{ V}$ ,  $0.1 \mu\text{F}$  Chip Capacitor between  $V_P$  and  $V_N$ )

# CM1213A, SZCM1213A

## PERFORMANCE INFORMATION (CONT'D)

Typical Filter Performance (nominal conditions unless specified otherwise, 50 Ohm Environment)

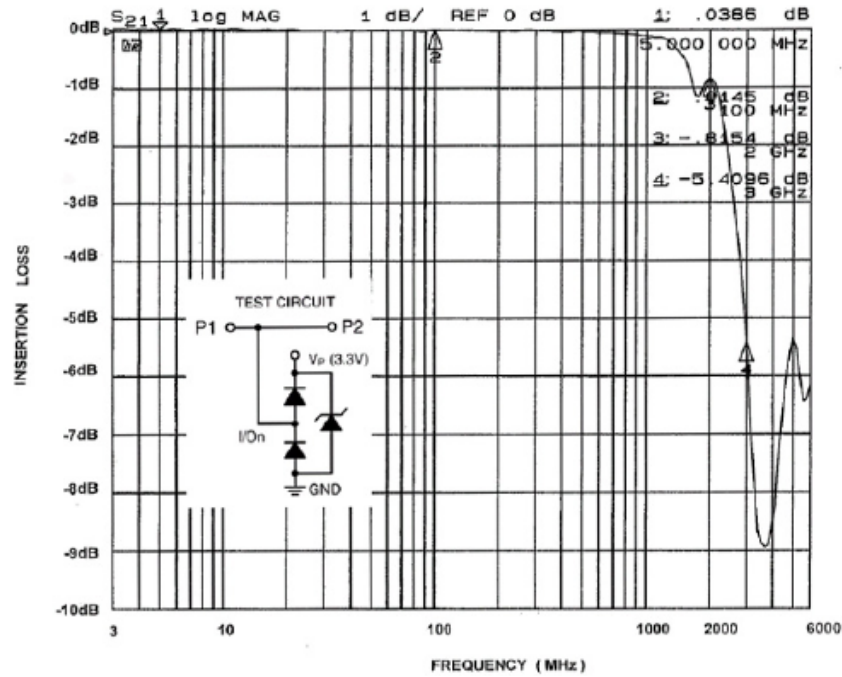


Figure 3. Insertion Loss (S21) vs. Frequency (0 V DC Bias,  $V_p=3.3$  V)

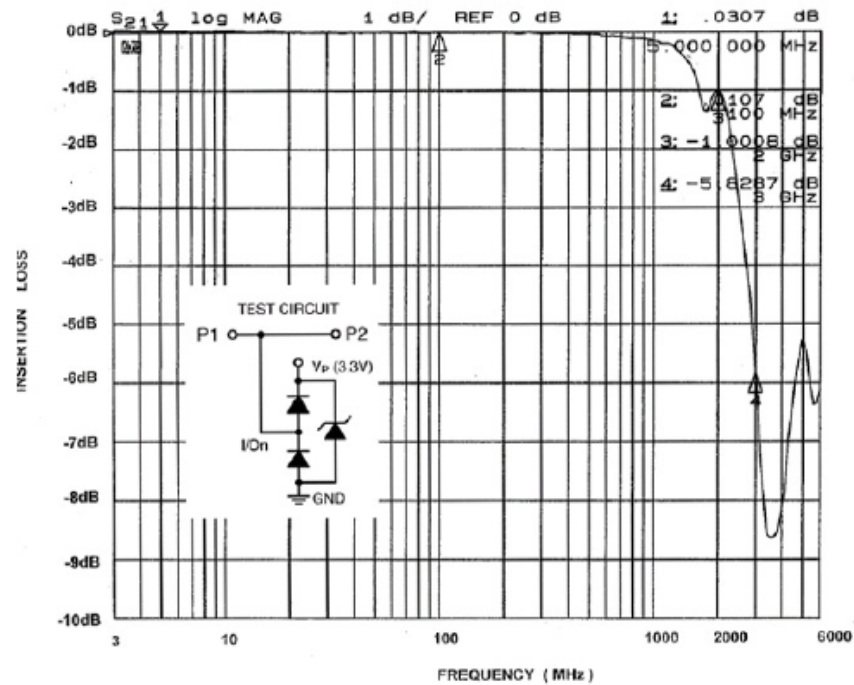


Figure 4. Insertion Loss (S21) vs. Frequency (2.5 V DC Bias,  $V_p=3.3$  V)

APPLICATION INFORMATION

**Design Considerations**

In order to realize the maximum protection against ESD pulses, care must be taken in the PCB layout to minimize parasitic series inductances on the Supply/Ground rails as well as the signal trace segment between the signal input (typically a connector) and the ESD protection device. Refer to Application of Positive ESD Pulse between Input Channel and Ground, which illustrates an example of a positive ESD pulse striking an input channel. The parasitic series inductance back to the power supply is represented by  $L_1$  and  $L_2$ . The voltage  $V_{CL}$  on the line being protected is:

$$V_{CL} = \text{Fwd Voltage Drop of } D_1 + V_{SUPPLY} + L_1 \times d(I_{ESD}) / dt + L_2 \times d(I_{ESD}) / dt$$

where  $I_{ESD}$  is the ESD current pulse, and  $V_{SUPPLY}$  is the positive supply voltage.

An ESD current pulse can rise from zero to its peak value in a very short time. As an example, a level 4 contact discharge per the IEC61000-4-2 standard results in a current pulse that rises from zero to 30 Amps in 1 ns. Here  $d(I_{ESD})/dt$  can be approximated by  $\Delta I_{ESD}/\Delta t$ , or  $30/(1 \times 10^{-9})$ . So just 10 nH of series inductance ( $L_1$  and  $L_2$  combined) will lead to a 300 V increment in  $V_{CL}$ !

Similarly for negative ESD pulses, parasitic series inductance from the  $V_N$  pin to the ground rail will lead to drastically increased negative voltage on the line being protected.

The CM1213A has an integrated Zener diode between  $V_P$  and  $V_N$ . This greatly reduces the effect of supply rail inductance  $L_2$  on  $V_{CL}$  by clamping  $V_P$  at the breakdown voltage of the Zener diode. However, for the lowest possible  $V_{CL}$ , especially when  $V_P$  is biased at a voltage significantly below the Zener breakdown voltage, it is recommended that a 0.22  $\mu F$  ceramic chip capacitor be connected between  $V_P$  and the ground plane.

As a general rule, the ESD Protection Array should be located as close as possible to the point of entry of expected electrostatic discharges. The power supply bypass capacitor mentioned above should be as close to the  $V_P$  pin of the Protection Array as possible, with minimum PCB trace lengths to the power supply, ground planes and between the signal input and the ESD device to minimize stray series inductance.

**Additional Information**

See also onsemi Application Note “Design Considerations for ESD Protection”, in the Applications section.

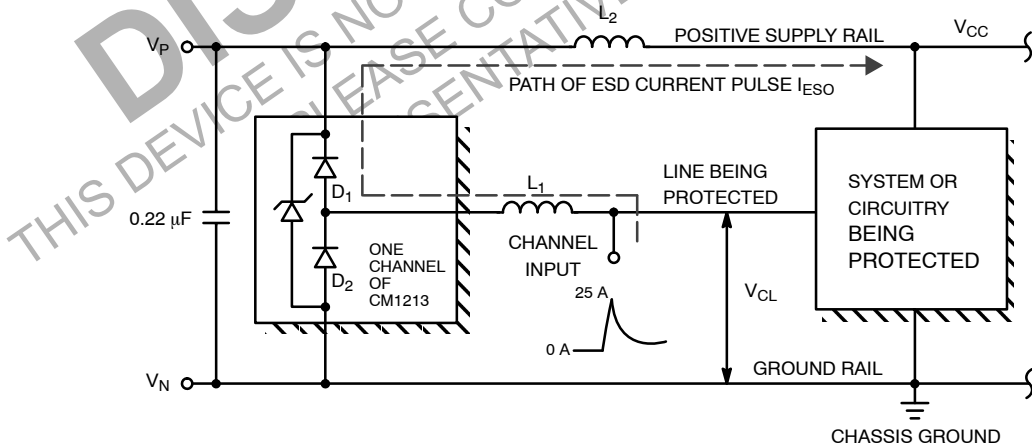
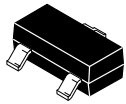


Figure 5. Application of Positive ESD Pulse between Input Channel and Ground

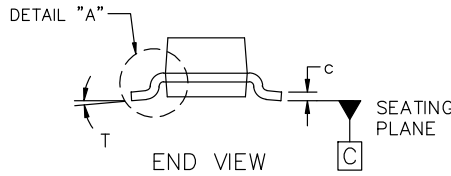
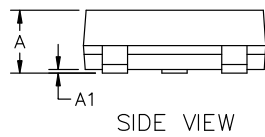
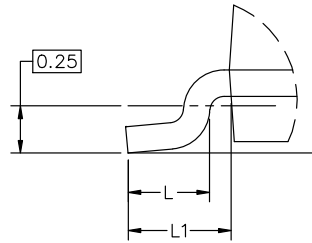
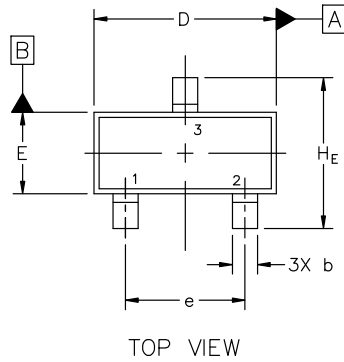




SCALE 4:1

**SOT-23 (TO-236) 2.90x1.30x1.00 1.90P**  
**CASE 318**  
**ISSUE AU**

DATE 14 AUG 2024

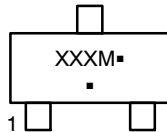


| MILLIMETERS |      |      |      |
|-------------|------|------|------|
| DIM         | MIN  | NOM  | MAX  |
| A           | 0.89 | 1.00 | 1.11 |
| A1          | 0.01 | 0.06 | 0.10 |
| b           | 0.37 | 0.44 | 0.50 |
| c           | 0.08 | 0.14 | 0.20 |
| D           | 2.80 | 2.90 | 3.04 |
| E           | 1.20 | 1.30 | 1.40 |
| e           | 1.78 | 1.90 | 2.04 |
| L           | 0.30 | 0.43 | 0.55 |
| L1          | 0.35 | 0.54 | 0.69 |
| HE          | 2.10 | 2.40 | 2.64 |
| T           | 0°   | ---  | 10°  |

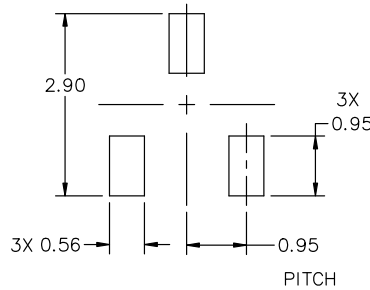
NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 2018.
2. CONTROLLING DIMENSIONS: MILLIMETERS.
3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF THE BASE MATERIAL.
4. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

**GENERIC MARKING DIAGRAM\***



XXX = Specific Device Code  
M = Date Code  
▪ = Pb-Free Package



\* For additional information on our Pb-Free strategy and soldering details, please download the onsemi Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "▪", may or may not be present. Some products may not follow the Generic Marking.

**STYLES ON PAGE 2**

|                         |   |  |
|-------------------------|---|--|
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| <b>DESCRIPTION:</b>     | <b>SOT-23 (TO-236) 2.90x1.30x1.00 1.90P</b> | <b>PAGE 1 OF 2</b>   |

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**SOT-23 (TO-236) 2.90x1.30x1.00 1.90P**  
**CASE 318**  
**ISSUE AU**

DATE 14 AUG 2024

STYLE 1 THRU 5:  
CANCELLED

STYLE 6:  
PIN 1. BASE  
2. EMITTER  
3. COLLECTOR

STYLE 7:  
PIN 1. EMITTER  
2. BASE  
3. COLLECTOR

STYLE 8:  
PIN 1. ANODE  
2. NO CONNECTION  
3. CATHODE

STYLE 9:  
PIN 1. ANODE  
2. ANODE  
3. CATHODE

STYLE 10:  
PIN 1. DRAIN  
2. SOURCE  
3. GATE

STYLE 11:  
PIN 1. ANODE  
2. CATHODE  
3. CATHODE-ANODE

STYLE 12:  
PIN 1. CATHODE  
2. CATHODE  
3. ANODE

STYLE 13:  
PIN 1. SOURCE  
2. DRAIN  
3. GATE

STYLE 14:  
PIN 1. CATHODE  
2. GATE  
3. ANODE

STYLE 15:  
PIN 1. GATE  
2. CATHODE  
3. ANODE

STYLE 16:  
PIN 1. ANODE  
2. CATHODE  
3. CATHODE

STYLE 17:  
PIN 1. NO CONNECTION  
2. ANODE  
3. CATHODE

STYLE 18:  
PIN 1. NO CONNECTION  
2. CATHODE  
3. ANODE

STYLE 19:  
PIN 1. CATHODE  
2. ANODE  
3. CATHODE-ANODE

STYLE 20:  
PIN 1. CATHODE  
2. ANODE  
3. GATE

STYLE 21:  
PIN 1. GATE  
2. SOURCE  
3. DRAIN

STYLE 22:  
PIN 1. RETURN  
2. OUTPUT  
3. INPUT

STYLE 23:  
PIN 1. ANODE  
2. ANODE  
3. CATHODE

STYLE 24:  
PIN 1. GATE  
2. DRAIN  
3. SOURCE

STYLE 25:  
PIN 1. ANODE  
2. CATHODE  
3. GATE

STYLE 26:  
PIN 1. CATHODE  
2. ANODE  
3. NO CONNECTION

STYLE 27:  
PIN 1. CATHODE  
2. CATHODE  
3. CATHODE

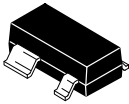
STYLE 28:  
PIN 1. ANODE  
2. ANODE  
3. ANODE

|                         |   |   |
|-------------------------|---|---|
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| <b>DESCRIPTION:</b>     | <b>SOT-23 (TO-236) 2.90x1.30x1.00 1.90P</b> | <b>PAGE 2 OF 2</b>  |

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# MECHANICAL CASE OUTLINE PACKAGE DIMENSIONS

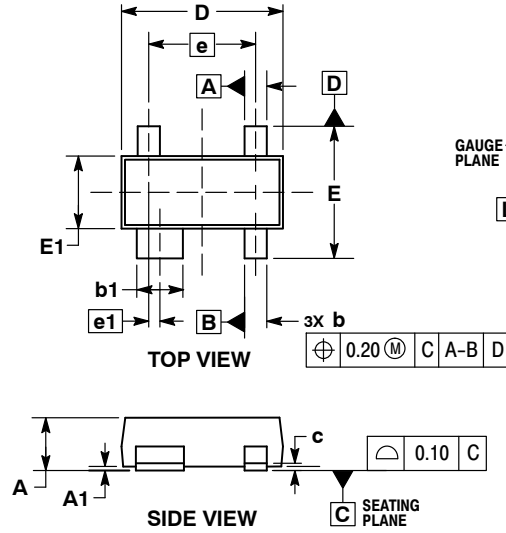
ON Semiconductor®



SCALE 4:1

## SOT-143 CASE 318A-06 ISSUE U

DATE 07 SEP 2011

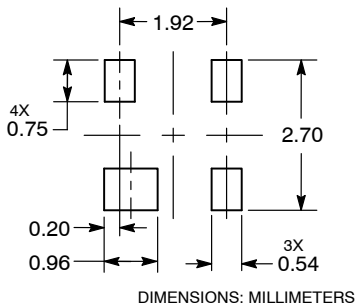


**NOTES:**

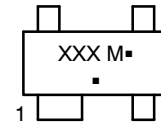
1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETERS.
3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
4. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS. MOLD FLASH, PROTRUSIONS, AND GATE BURRS SHALL NOT EXCEED 0.25 PER SIDE. DIMENSION E1 DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH AND PROTRUSION SHALL NOT EXCEED 0.25 PER SIDE.
5. DIMENSIONS D AND E1 ARE DETERMINED AT DATUM H.
6. DATUMS A AND B ARE DETERMINED AT DATUM H.

| DIM | MILLIMETERS |      |
|-----|-------------|------|
|     | MIN         | MAX  |
| A   | 0.80        | 1.12 |
| A1  | 0.01        | 0.15 |
| b   | 0.30        | 0.51 |
| b1  | 0.76        | 0.94 |
| c   | 0.08        | 0.20 |
| D   | 2.80        | 3.05 |
| E   | 2.10        | 2.64 |
| E1  | 1.20        | 1.40 |
| e   | 1.92 BSC    |      |
| e1  | 0.20 BSC    |      |
| L   | 0.35        | 0.70 |
| L2  | 0.25 BSC    |      |

### RECOMMENDED SOLDERING FOOTPRINT



### GENERIC MARKING DIAGRAM\*



XXX = Specific Device Code  
M = Date Code  
▪ = Pb-Free Package

(Note: Microdot may be in either location)

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "▪", may or may not be present.

- |   |   |   |   |  |  |
|---|---|---|---|--|--|
| <p><b>STYLE 1:</b><br/>PIN 1. COLLECTOR<br/>2. EMITTER<br/>3. EMITTER<br/>4. BASE</p> | <p><b>STYLE 2:</b><br/>PIN 1. SOURCE<br/>2. DRAIN<br/>3. GATE 1<br/>4. GATE 2</p> | <p><b>STYLE 3:</b><br/>PIN 1. GROUND<br/>2. SOURCE<br/>3. INPUT<br/>4. OUTPUT</p> | <p><b>STYLE 4:</b><br/>PIN 1. OUTPUT<br/>2. GROUND<br/>3. GROUND<br/>4. INPUT</p> | <p><b>STYLE 5:</b><br/>PIN 1. SOURCE<br/>2. DRAIN<br/>3. GATE 1<br/>4. SOURCE</p>  | <p><b>STYLE 6:</b><br/>PIN 1. GND<br/>2. RF IN<br/>3. VREG<br/>4. RF OUT</p> |
| <p><b>STYLE 7:</b><br/>PIN 1. SOURCE<br/>2. GATE<br/>3. DRAIN<br/>4. SOURCE</p>       | <p><b>STYLE 8:</b><br/>PIN 1. SOURCE<br/>2. GATE<br/>3. DRAIN<br/>4. N/C</p>      | <p><b>STYLE 9:</b><br/>PIN 1. GND<br/>2. IOUT<br/>3. VCC<br/>4. VREF</p>          | <p><b>STYLE 10:</b><br/>PIN 1. DRAIN<br/>2. N/C<br/>3. SOURCE<br/>4. GATE</p>     | <p><b>STYLE 11:</b><br/>PIN 1. SOURCE<br/>2. GATE 1<br/>3. GATE 2<br/>4. DRAIN</p> |  |

|                         |                    |  |
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| <b>DESCRIPTION:</b>     | <b>SOT-143</b>     | <b>PAGE 1 OF 1</b>   |

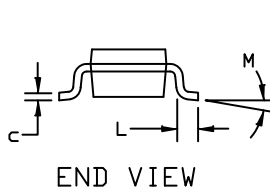
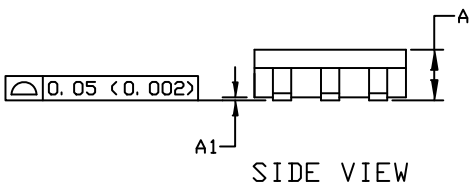
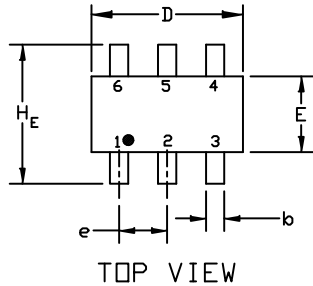
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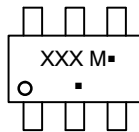
SCALE 2:1

SC-74  
CASE 318F  
ISSUE P

DATE 07 OCT 2021



GENERIC  
MARKING DIAGRAM\*



XXX = Specific Device Code  
M = Date Code  
▪ = Pb-Free Package

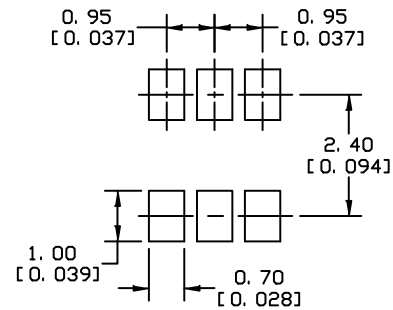
(Note: Microdot may be in either location)

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "▪", may or may not be present. Some products may not follow the Generic Marking.

NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994
2. CONTROLLING DIMENSION: INCHES
3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF THE BASE MATERIAL.

| DIM | MILLIMETERS |      |      | INCHES |       |       |
|-----|-------------|------|------|--------|-------|-------|
|     | MIN.        | NOM. | MAX. | MIN.   | NOM.  | MAX.  |
| A   | 0.90        | 1.00 | 1.10 | 0.035  | 0.039 | 0.043 |
| A1  | 0.01        | 0.06 | 0.10 | 0.001  | 0.002 | 0.004 |
| b   | 0.25        | 0.37 | 0.50 | 0.010  | 0.015 | 0.020 |
| c   | 0.10        | 0.18 | 0.26 | 0.004  | 0.007 | 0.010 |
| D   | 2.90        | 3.00 | 3.10 | 0.114  | 0.118 | 0.122 |
| E   | 1.30        | 1.50 | 1.70 | 0.051  | 0.059 | 0.067 |
| e   | 0.85        | 0.95 | 1.05 | 0.034  | 0.037 | 0.041 |
| HE  | 2.50        | 2.75 | 3.00 | 0.099  | 0.108 | 0.118 |
| L   | 0.20        | 0.40 | 0.60 | 0.008  | 0.016 | 0.024 |
| M   | 0*          | ---  | 10*  | 0*     | ---   | 10*   |



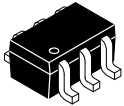
\* For additional information on our Pb-Free strategy and soldering details, please download the DN Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERM/D.

SOLDERING FOOTPRINT

|   |  |   |  |   |   |
|---|--|---|--|---|---|
| <p>STYLE 1:<br/>PIN 1. CATHODE<br/>2. ANODE<br/>3. CATHODE<br/>4. CATHODE<br/>5. ANODE<br/>6. CATHODE</p>     | <p>STYLE 2:<br/>PIN 1. NO CONNECTION<br/>2. COLLECTOR<br/>3. EMITTER<br/>4. NO CONNECTION<br/>5. COLLECTOR<br/>6. BASE</p> | <p>STYLE 3:<br/>PIN 1. EMITTER 1<br/>2. BASE 1<br/>3. COLLECTOR 2<br/>4. EMITTER 2<br/>5. BASE 2<br/>6. COLLECTOR 1</p> | <p>STYLE 4:<br/>PIN 1. COLLECTOR 2<br/>2. EMITTER 1/EMITTER 2<br/>3. COLLECTOR 1<br/>4. EMITTER 3<br/>5. BASE 1/BASE 2/COLLECTOR 3<br/>6. BASE 3</p> | <p>STYLE 5:<br/>PIN 1. CHANNEL 1<br/>2. ANODE<br/>3. CHANNEL 2<br/>4. CHANNEL 3<br/>5. CATHODE<br/>6. CHANNEL 4</p> | <p>STYLE 6:<br/>PIN 1. CATHODE<br/>2. ANODE<br/>3. CATHODE<br/>4. CATHODE<br/>5. CATHODE<br/>6. CATHODE</p> |
| <p>STYLE 7:<br/>PIN 1. SOURCE 1<br/>2. GATE 1<br/>3. DRAIN 2<br/>4. SOURCE 2<br/>5. GATE 2<br/>6. DRAIN 1</p> | <p>STYLE 8:<br/>PIN 1. EMITTER 1<br/>2. BASE 2<br/>3. COLLECTOR 2<br/>4. EMITTER 2<br/>5. BASE 1<br/>6. COLLECTOR 1</p>    | <p>STYLE 9:<br/>PIN 1. EMITTER 2<br/>2. BASE 2<br/>3. COLLECTOR 1<br/>4. EMITTER 1<br/>5. BASE 1<br/>6. COLLECTOR 2</p> | <p>STYLE 10:<br/>PIN 1. ANODE/CATHODE<br/>2. BASE<br/>3. EMITTER<br/>4. COLLECTOR<br/>5. ANODE<br/>6. CATHODE</p>                                    | <p>STYLE 11:<br/>PIN 1. EMITTER<br/>2. BASE<br/>3. ANODE/CATHODE<br/>4. ANODE<br/>5. CATHODE<br/>6. COLLECTOR</p>   |   |

|                  |             |  |
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| DESCRIPTION:     | SC-74       | PAGE 1 OF 1  |

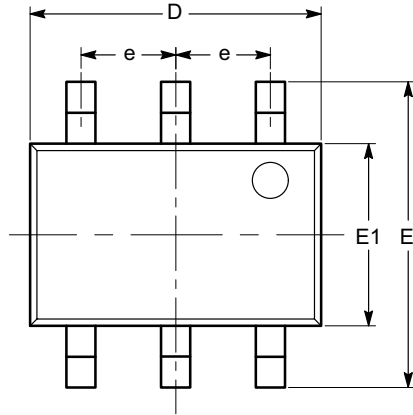
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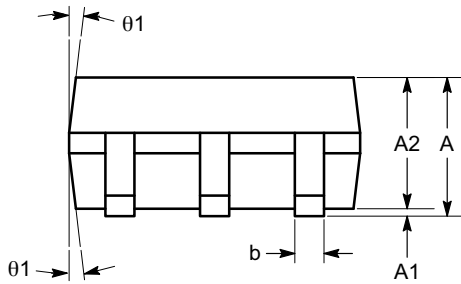
**SC-88 (SC-70 6 Lead), 1.25x2**  
**CASE 419AD**  
**ISSUE A**

DATE 07 JUL 2010

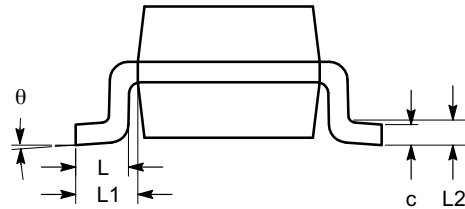


TOP VIEW

| SYMBOL     | MIN      | NOM  | MAX  |
|------------|----------|------|------|
| A          | 0.80     |      | 1.10 |
| A1         | 0.00     |      | 0.10 |
| A2         | 0.80     |      | 1.00 |
| b          | 0.15     |      | 0.30 |
| c          | 0.10     |      | 0.18 |
| D          | 1.80     | 2.00 | 2.20 |
| E          | 1.80     | 2.10 | 2.40 |
| E1         | 1.15     | 1.25 | 1.35 |
| e          | 0.65 BSC |      |      |
| L          | 0.26     | 0.36 | 0.46 |
| L1         | 0.42 REF |      |      |
| L2         | 0.15 BSC |      |      |
| $\theta$   | 0°       |      | 8°   |
| $\theta_1$ | 4°       |      | 10°  |



SIDE VIEW



END VIEW

**Notes:**

- (1) All dimensions are in millimeters. Angles in degrees.
- (2) Complies with JEDEC MO-203.

|                         |                                     |  |
|-------------------------|-------------------------------------|--|
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| <b>DESCRIPTION:</b>     | <b>SC-88 (SC-70 6 LEAD), 1.25X2</b> | <b>PAGE 1 OF 1</b>   |

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